Over Voltage and Over Current Protection IC

General Description

HM4808 is an Over-Voltage-Protection (OVP) and Over-Current-Protection (OCP) device. It can disconnect IN to OUT to protect load in case wrong input operating conditions are detected. The system is positive over-voltage protected up to 36V. The internal over-voltage thresholds (OVLO) is 6.1V and internal over-current thresholds (OCP) is 2.5A. HM4808 also has internal over temperature protect(OTP) function and it can monitor chip temperature to protect the device.

The device is packaged in advanced full-Green SOT23-6 package .

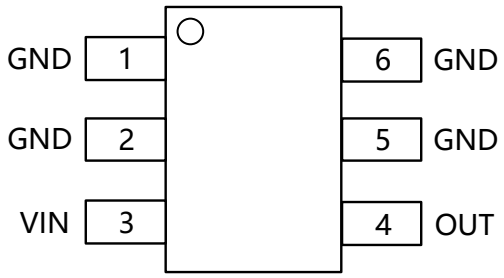
Features

- Typical R_{ON} is110mΩ N-Channel MOSFET @5V/1A
- V_{IN} Operating Range: 2.5V to 36V
- Internal Over-voltage Lockout : 6.1V
- Internal Over-current Lockout : 2.5A (MIN)
- Over-voltage-Protection Response Time：<500ns
- Startup Debounce Time: 16ms (TYP).
- Typical Output Power on Time: 16.3ms (TYP).
- Internal Thermal-Shutdown Protection
- All pins ESD Protected: Human Body Model (JESD22-A114) ± 2KV Pass
- SOT23-6 package

Application

- GPS and Navigation Equipment
- Portable Media Devices, Laptop & MID
- SLR Digital Cameras
- Industrial Handheld and Enterprise Equipment

Pin Configuration



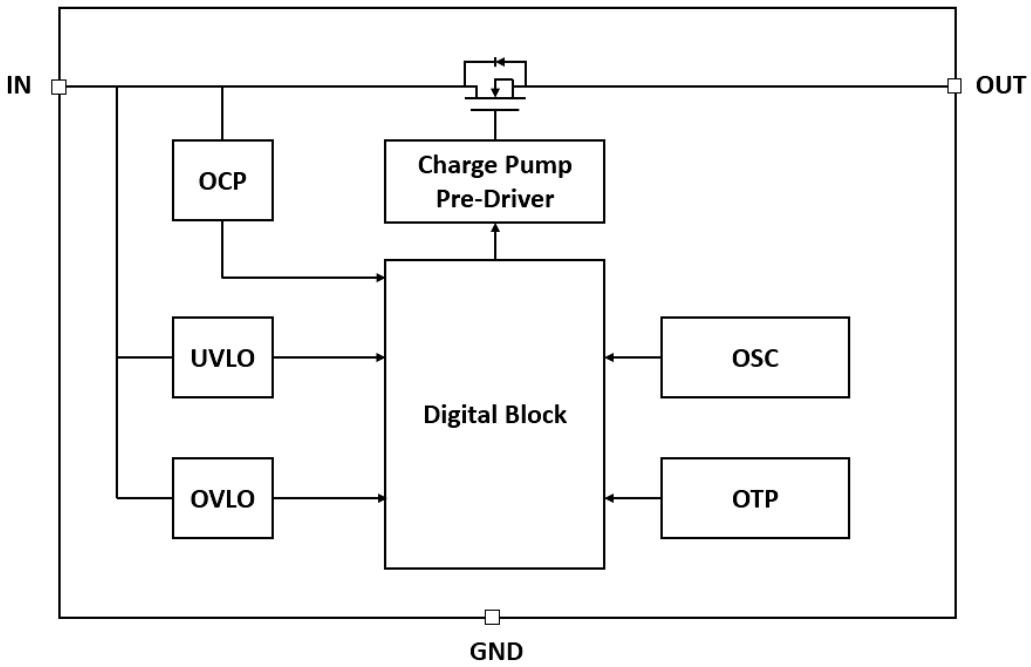
Top View

Pin Function

Pin No.	Name	Description
3	VIN	Input Voltage Pin.
1, 2, 5, 6[(1)]	GND	Ground. Connect GND pins together for proper operation.
4	OUT	Load Output Pin .

Note1: PIN 1,5,6 can be floated if necessary.

Block Diagram



Functional Description

The OVP switch with over-voltage protection feature a low 110mΩ (typical) on-resistance(R_{ON}) internal FET and protect low-voltage systems against voltage faults up to 36V_{DC}. The internal over-voltage thresholds (OVLO) is 6.1V and internal over-current thresholds (OCP) is 2.5A (MIN).

The internal FET turns off when the junction temperature exceeds +155 ºC (TYP). The device exits thermal shutdown after the junction temperature cools by 20 ºC (TYP.).

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor 1uF or lager must be placed between the VIN and GND pins.

Output Capacitor

A 1uF or lager capacitor should be placed between the OUT and GND pins.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters	Min	Max	Unit
V_{IN}	IN to GND	-0.3	36	V
V_{OUT}	OUT to GND	-0.3	28	V
I_{SW1}	Maximum Continuous Current of switch IN-OUT		2.5	A
I_{SW2}	Maximum Peak Current of switch IN-OUT(10ms)		4.0	A
P_D	Power Dissipation at T_A= +70℃		500	mW
T_{STG}	Storage Junction Temperature	-65	+150	℃
T_A	Operating Temperature Range	-40	+85	℃
T_{SOLD}	Soldering Temperature (reflow).		+260	℃
T_J	Junction Temperature		+150	℃

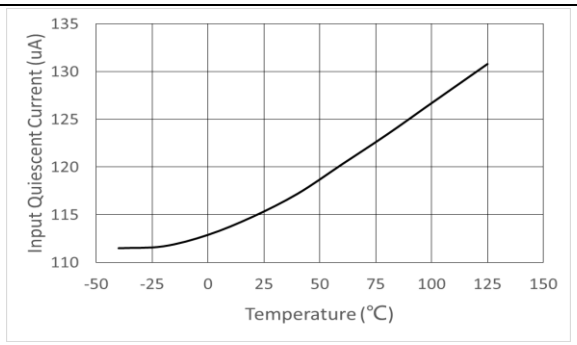
Electrical Characteristics

Unless otherwise noted, typical values are at V_{IN}=5.0V and T_A=25℃ .

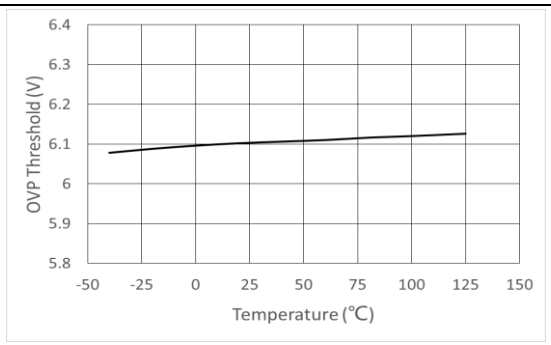
Symbol	Parameters	Conditions	Min	Typ	Max	Unit
Basic Operation						
V_{IN}	Input Voltage		2.5		36	V
I_{IN}	V_{IN} Quiescent Current	V_{IN}=5.0V, OUT floating		110		μA
R_{ON}	On-Resistance of Switch IN-OUT	V_{IN}=5.0V, I_{OUT}=1A		110		mΩ
R_{DIS}	Output Discharge Resistance			3.9		KΩ
V_{OVLO}	Over-voltage protect of V_{IN}	V_{IN} rise up	5.8	6.1	6.4	V
V_{OVLO_HYS}	Over-voltage Protect Hysteresis of V_{IN}			0.15		V
V_{UVLO_R}	Under Voltage Lockout Threshold	V_{IN} rising		2.2		V
Input Over						
t_{DEB}	Debounce Time	Time from 2.1V<V_{IN}< V_{OVLO} to V_{OUT}=10% of V_{IN}		16		ms
t_{ON}	Switch Turn-On Time	R_L=100Ω, C_L=22uF, V_{OUT} from 0.1×V_{IN} to 0.9×V_{IN}		0.3		ms
t_{ON_ALL}	Output power-on Time	Time from 2.1V<V_{IN}< V_{OVLO} to V_{OUT}=90% of V_{IN}		16.3		ms
t_{OFF_RES}[(2)]	Switch turn-off response time	V_{IN} > V_{OVLO} to V_{OUT} stop rising		150	300	ns
Dynamic Characteristics: see figure						
I_{OCP}	Over current protect		2.5	3.1		A
I_{SHORT}	Short current protect			120		mA
t_{OCP}	OCP debounce time			30		ms
T_{REC_OCP}	OCP recovery time			1		s
Over Temperature Protection（OTP）[(2)]						
T_{SHDN}	Thermal Shutdown			155		℃
T_{SHDN_HYS}	Thermal-shutdown Hysteresis			20		℃

Note2： Guaranteed by characterization and design.

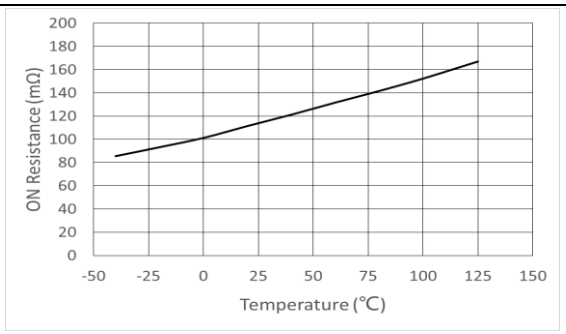
Typical Characteristics



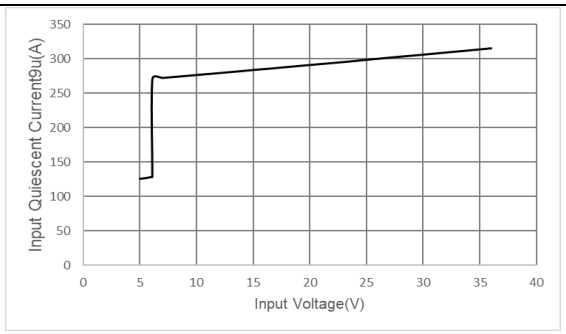
Input Quiescent Current vs.Temperature



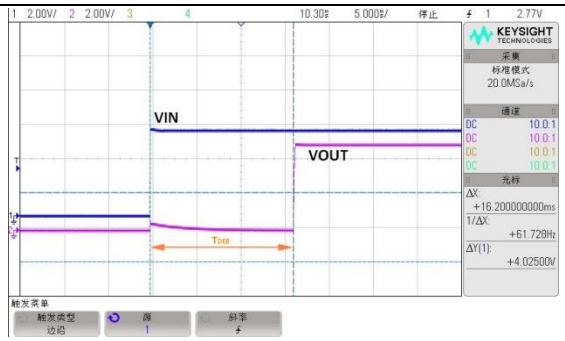
OVP threshold vs. Temperature



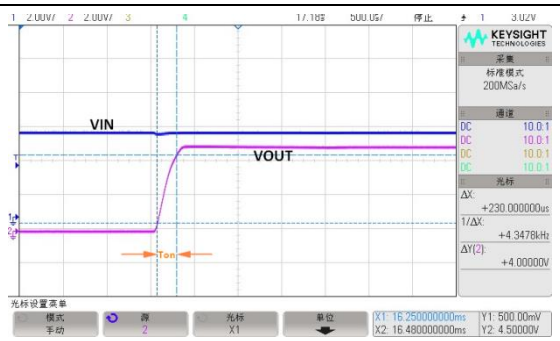
On Resistance vs. Temperature



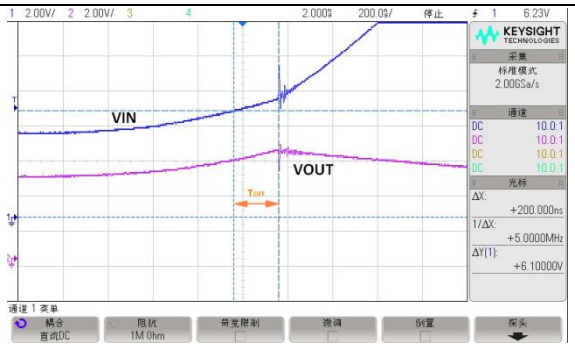
Input Quiescent Current vs. Input Voltage



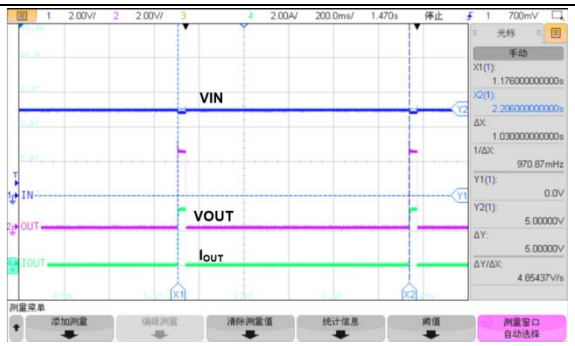
Power ON Debounce Time



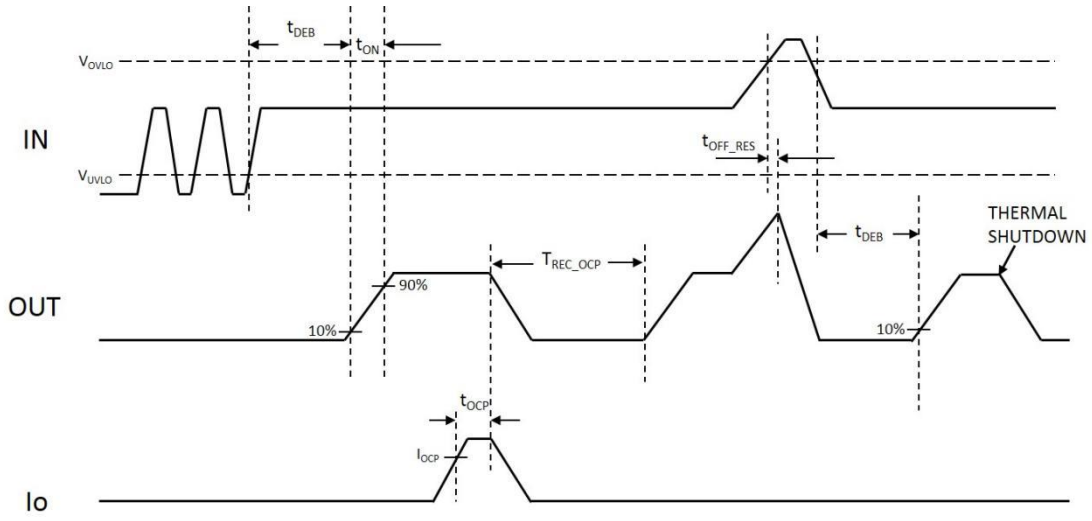
Switch Turn-on Time



OVP Turn-off Response Time

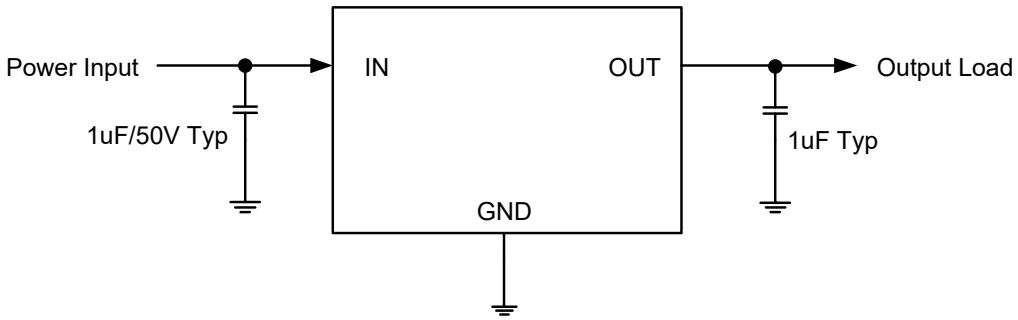


OCP Recovery



Note: Waveform are not to scale

Application Circuits



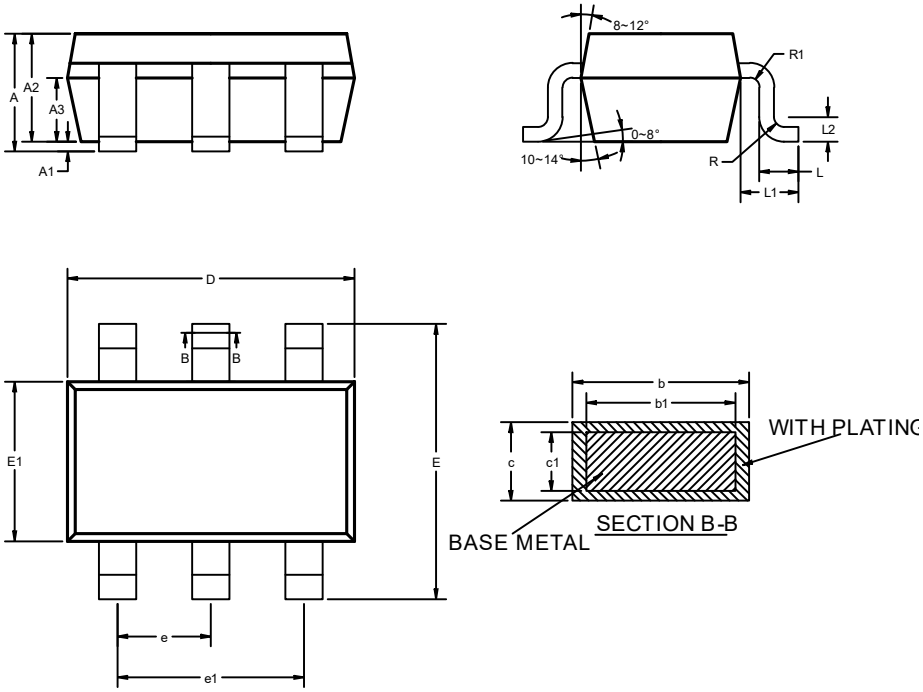
Note*:

Reference input and output capacitance value is 1uF.

This electric circuit only supplies for reference.

Package Dimension

SOT23-6



(Units :mm)

SYMBOL	MIN	NOM	MAX
A	—	—	1.250
A1	0	—	0.150
A2	1.000	1.100	1.200
A3	0.600	0.650	0.700
b	0.360	—	0.450
b1	0.350	0.380	0.410
c	0.140	—	0.200
c1	0.140	0.150	0.160
D	2.826	2.926	3.026
E	2.600	2.800	3.000
E1	1.526	1.626	1.726
e	0.900	0.950	1.000
e1	1.800	1.900	2.000
L	0.300	0.400	0.500
L1	0.590REF		
L2	0.250BSC		
R	0.050	—	0.200
R1	0.050	—	0.200